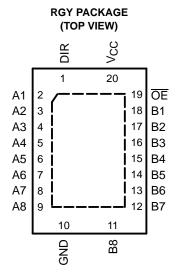
SCES271D-APRIL 1999-REVISED JULY 2004

### **FEATURES**

- Operates from 1.65 V to 3.6 V
- Max t<sub>pd</sub> of 3.4 ns at 3.3 V

DGV, DW, NS, OR PW PACKAGE (TOP VIEW) DIR [ 20 V<sub>CC</sub> А1 П 19 \ OE A2 **∏** 18 T B1 3 АЗ Г 17 П в2 16 ∏ B3 A4 **∏** 15 B4 A5 **∏** 6 14 N B5 А6 П A7 🛮 8 13**∏** B6 A8 🛮 9 12 B7 GND  $\Pi$ 10 11 B8

- ±24-mA Output Drive at 3.3 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17



### **DESCRIPTION/ORDERING INFORMATION**

This octal bus transceiver is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The SN74ALVC245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable  $(\overline{OE})$  input can be used to disable the device so the buses are effectively isolated.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

### **ORDERING INFORMATION**

| T <sub>A</sub> | PAG         | CKAGE <sup>(1)</sup> | ORDERABLE PART NUMBER | TOP-SIDE MARKING |  |
|----------------|-------------|----------------------|-----------------------|------------------|--|
|                | QFN - RGY   |                      | SN74ALVC245RGYR       | VA245            |  |
|                | SOIC - DW   | Tube                 | SN74ALVC245DW         | ALVC245          |  |
|                | SOIC - DW   | Tape and reel        | SN74ALVC245DWR        | ALVO245          |  |
| -40°C to 85°C  | SOP - NS    | Tape and reel        | SN74ALVC245NSR        | ALVC245          |  |
|                | TCCOD DW    | Tube                 | SN74ALVC245PW         | 1/4045           |  |
|                | TSSOP - PW  | Tape and reel        | SN74ALVC245PWR        | ── VA245         |  |
|                | TVSOP - DGV | Tape and reel        | SN74ALVC245DGVR       | VA245            |  |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



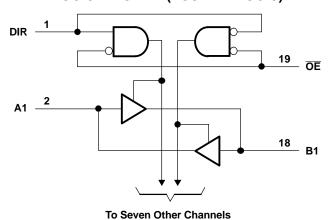
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### **FUNCTION TABLE**

| INP | UTS | OPERATION       |
|-----|-----|-----------------|
| ŌĒ  | DIR | OPERATION       |
| L   | L   | B data to A bus |
| L   | Н   | A data to B bus |
| Н   | X   | Isolation       |

### **LOGIC DIAGRAM (POSITIVE LOGIC)**



# **ABSOLUTE MAXIMUM RATINGS(1)**

over operating free-air temperature range (unless otherwise noted)

|                  |   |                                 | MIN  | MAX                   | UNIT |
|------------------|---|---------------------------------|------|-----------------------|------|
| V <sub>CC</sub>  | Supply voltage range                              |                                 | -0.5 | 4.6                   | V    |
| .,               | land valence recent                               | Except I/O ports <sup>(2)</sup> | -0.5 | 4.6                   |      |
| V <sub>I</sub>   | Input voltage range                               | I/O ports <sup>(2)(3)</sup>     | -0.5 | V <sub>CC</sub> + 0.5 | V    |
| Vo               | Output voltage range <sup>(2)(3)</sup>            | ·                               | -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>  | Input clamp current                               | V <sub>1</sub> < 0              |      | -50                   | mA   |
| I <sub>OK</sub>  | Output clamp current                              | V <sub>O</sub> < 0              |      | -50                   | mA   |
| Io               | Continuous output current                         |                                 |      | ±50                   | mA   |
|                  | Continuous current through V <sub>CC</sub> or GND |                                 |      | ±100                  | mA   |
|                  |   | DGV package <sup>(4)</sup>      |      | 92                    |      |
|                  |   | DW package (4)                  |      | 58                    |      |
| $\theta_{JA}$    | Package thermal impedance                         | NS package (4)                  |      | 60                    | °C/W |
|                  |   | PW package <sup>(4)</sup>       |      | 83                    |      |
|                  |   | RGY package <sup>(5)</sup>      |      | 37                    | 1    |
| T <sub>stg</sub> | Storage temperature range                         | •                               | -65  | 150                   | °C   |

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

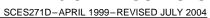
<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V, maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

<sup>5)</sup> The package thermal impedance is calculated in accordance with JESD 51-5.







# **RECOMMENDED OPERATING CONDITIONS**(1)

|                 |                                    |  | MIN                  | MAX                  | UNIT |
|-----------------|------------------------------------|--|----------------------|----------------------|------|
| V <sub>CC</sub> | Supply voltage                     |  | 1.65                 | 3.6                  | V    |
|                 |                                    | V <sub>CC</sub> = 1.65 V to 1.95 V           | $0.65 \times V_{CC}$ |                      |      |
| $V_{IH}$        | High-level input voltage           | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$   | 1.7                  |                      | V    |
|                 |                                    | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$   | 2                    |                      |      |
|                 |                                    | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ |                      | $0.35 \times V_{CC}$ |      |
| $V_{IL}$        | Low-level input voltage            | V <sub>CC</sub> = 2.3 V to 2.7 V             |                      | 0.7                  | V    |
|                 |                                    | V <sub>CC</sub> = 2.7 V to 3.6 V             |                      | 0.8                  |      |
| V <sub>I</sub>  | Input voltage                      | •  | 0                    | V <sub>cc</sub>      | V    |
| Vo              | Output voltage                     |  | 0                    | V <sub>CC</sub>      | V    |
|                 |                                    | V <sub>CC</sub> = 1.65 V                     |                      | -4                   |      |
|                 | High lavel autout august           | V <sub>CC</sub> = 2.3 V                      |                      | -12                  | mA   |
| I <sub>OH</sub> | High-level output current          | V <sub>CC</sub> = 2.7 V                      |                      | -12                  |      |
|                 |                                    | V <sub>CC</sub> = 3 V                        |                      | -24                  |      |
|                 |                                    | V <sub>CC</sub> = 1.65 V                     |                      | 4                    |      |
|                 | Lave lavel autout average          | V <sub>CC</sub> = 2.3 V                      |                      | 12                   | A    |
| I <sub>OL</sub> | Low-level output current           | current $V_{CC} = 2.7 \text{ V}$             |                      | 12                   | mA   |
|                 |                                    | V <sub>CC</sub> = 3 V                        |                      | 24                   |      |
| Δt/Δν           | Input transition rise or fall rate | ·  |                      | 10                   | ns/V |
| T <sub>A</sub>  | Operating free-air temperature     |  | -40                  | 85                   | °C   |

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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# **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER                      | TEST CONDITIONS  | V <sub>cc</sub> | MIN                   | TYP <sup>(1)</sup> | MAX  | UNIT |
|--------------------------------|--|-----------------|-----------------------|--------------------|------|------|
|                                | $I_{OH} = -100 \mu A$  | 1.65 V to 3.6 V | V <sub>CC</sub> - 0.2 |                    |      |      |
|                                | $I_{OH} = -4 \text{ mA}$                                       | 1.65 V          | 1.2                   |                    |      |      |
|                                | I <sub>OH</sub> = -6 mA  | 2.3 V           | 2                     |                    |      |      |
| V <sub>OH</sub>                |  | 2.3 V           | 1.7                   |                    |      | V    |
|                                | I <sub>OH</sub> = -12 mA                                       | 2.7 V           | 2.2                   | ,                  |      |      |
|                                |  | 3 V             | 2.4                   |                    |      |      |
|                                | I <sub>OH</sub> = -24 mA                                       | 3 V             | 2                     |                    |      |      |
|                                | I <sub>OL</sub> = 100 μA                                       | 1.65 V to 3.6 V |                       |                    | 0.2  |      |
|                                | I <sub>OL</sub> = 4 mA   | 1.65 V          |                       |                    | 0.45 |      |
| N/                             | I <sub>OL</sub> = 6 mA   | 2.3 V           |                       | ,                  | 0.4  | \ /  |
| V <sub>OL</sub>                | 10 10  | 2.3 V           |                       |                    | 0.7  | V    |
|                                | I <sub>OL</sub> = 12 mA  | 2.7 V           |                       |                    | 0.4  |      |
|                                | I <sub>OL</sub> = 24 mA  | 3 V             |                       |                    | 0.55 |      |
| I <sub>I</sub>                 | $V_I = V_{CC}$ or GND  | 3.6 V           |                       |                    | ±5   | μΑ   |
| I <sub>OZ</sub> <sup>(2)</sup> | $V_O = V_{CC}$ or GND  | 3.6 V           |                       | ,                  | ±10  | μΑ   |
| I <sub>CC</sub>                | $V_I = V_{CC}$ or GND, $I_O = 0$                               | 3.6 V           |                       |                    | 10   | μΑ   |
| $\Delta I_{CC}$                | One input at $V_{CC}$ - 0.6 V, Other inputs at $V_{CC}$ or GND | 3 V to 3.6 V    |                       |                    | 750  | μА   |
| C <sub>i</sub> Control inputs  | $V_I = V_{CC}$ or GND  | 3.3 V           |                       | 4.5                |      | pF   |
| C <sub>io</sub> A or B ports   | $V_O = V_{CC}$ or GND  | 3.3 V           |                       | 11.5               |      | pF   |

# **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| PARAMETER        | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 1<br>± 0.15 | 1.8 V<br>5 V | V <sub>CC</sub> = 2<br>± 0.2 | 2.5 V<br>? V | V <sub>CC</sub> = 2 | 2.7 V | V <sub>CC</sub> = 3<br>± 0.3 | 3.3 V<br>5 V | UNIT |
|------------------|-----------------|----------------|-------------------------------|--------------|------------------------------|--------------|---------------------|-------|------------------------------|--------------|------|
|                  | (INFOT)         | (001701)       | MIN                           | MAX          | MIN                          | MAX          | MIN                 | MAX   | MIN                          | MAX          |      |
| t <sub>pd</sub>  | A or B          | B or A         | 1.5                           | 6            | 1                            | 3.5          |                     | 3.6   | 1.3                          | 3.4          | ns   |
| t <sub>en</sub>  | ŌĒ              | A or B         | 3.4                           | 8.6          | 2                            | 6            |                     | 6.3   | 1.6                          | 5.5          | ns   |
| t <sub>dis</sub> | ŌĒ              | A or B         | 2.7                           | 8            | 1                            | 4.8          |                     | 5.3   | 1.7                          | 5.5          | ns   |

# **OPERATING CHARACTERISTICS**

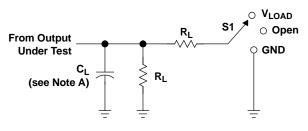
 $T_A = 25^{\circ}C$ 

| PARAMETE                    | R                | TEST CONDITIONS                          | V <sub>CC</sub> = 1.8 V<br>TYP | V <sub>CC</sub> = 2.5 V<br>TYP | V <sub>CC</sub> = 3.3 V<br>TYP | UNIT |  |
|-----------------------------|------------------|--|--------------------------------|--------------------------------|--------------------------------|------|--|
| Power dissipation           | Outputs enabled  | C _ 0 pE f _ 10 MHz                      | 25                             | 27                             | 30                             | pF   |  |
| capacitance per transceiver | Outputs disabled | $C_L = 0 \text{ pF, f} = 10 \text{ MHz}$ | 0                              | 0                              | 0                              | pF   |  |

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. (2) For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.



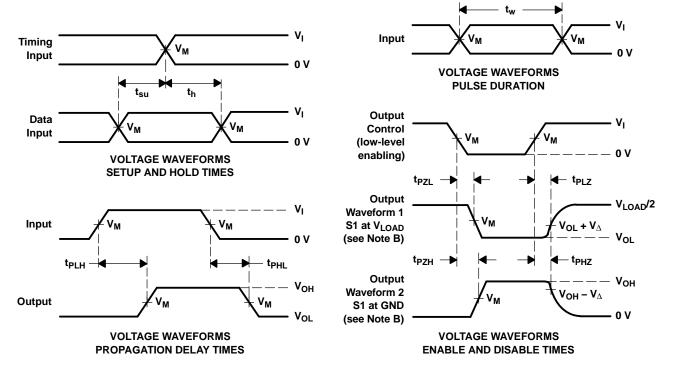
# PARAMETER MEASUREMENT INFORMATION



| TEST                               | <b>S</b> 1        |
|------------------------------------|-------------------|
| t <sub>pd</sub>                    | Open              |
| t <sub>PLZ</sub> /t <sub>PZL</sub> | V <sub>LOAD</sub> |
| t <sub>PHZ</sub> /t <sub>PZH</sub> | GND               |

**LOAD CIRCUIT** 

| V                 | IN              | PUT                            | V                  | , , , , , , , , , , , , , , , , , , , | •     | В              | , I                   |
|-------------------|-----------------|--------------------------------|--------------------|---------------------------------------|-------|----------------|-----------------------|
| V <sub>CC</sub>   | VI              | t <sub>r</sub> /t <sub>f</sub> | V <sub>M</sub>     | V <sub>LOAD</sub>                     | CL    | R <sub>L</sub> | $oldsymbol{V}_\Delta$ |
| 1.8 V ± 0.15 V    | V <sub>CC</sub> | ≤2 ns                          | V <sub>CC</sub> /2 | 2×V <sub>CC</sub>                     | 30 pF | <b>1 k</b> Ω   | 0.15 V                |
| 2.5 V $\pm$ 0.2 V | V <sub>CC</sub> | ≤2 ns                          | V <sub>CC</sub> /2 | 2×V <sub>CC</sub>                     | 30 pF | 500 Ω          | 0.15 V                |
| 2.7 V             | 2.7 V           | ≤2.5 ns                        | 1.5 V              | 6 V                                   | 50 pF | 500 Ω          | 0.3 V                 |
| 3.3 V $\pm$ 0.3 V | 2.7 V           | ≤2.5 ns                        | 1.5 V              | 6 V                                   | 50 pF | <b>500</b> Ω   | 0.3 V                 |



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{\Omega}$  = 50  $\Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

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#### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp       | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|---------------------|--------------|----------------------|---------|
|                  |        |              |                    |      |                |              | (6)                           |                     |              |                      |         |
| SN74ALVC245DGVR  | ACTIVE | TVSOP        | DGV                | 20   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | VA245                | Samples |
| SN74ALVC245DW    | ACTIVE | SOIC         | DW                 | 20   | 25             | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | ALVC245              | Samples |
| SN74ALVC245DWR   | ACTIVE | SOIC         | DW                 | 20   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | ALVC245              | Samples |
| SN74ALVC245NSR   | ACTIVE | SO           | NS                 | 20   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | ALVC245              | Samples |
| SN74ALVC245PW    | ACTIVE | TSSOP        | PW                 | 20   | 70             | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | VA245                | Samples |
| SN74ALVC245PWR   | ACTIVE | TSSOP        | PW                 | 20   | 2000           | RoHS & Green | NIPDAU                        | Level-1-260C-UNLIM  | -40 to 85    | VA245                | Samples |
| SN74ALVC245RGYR  | ACTIVE | VQFN         | RGY                | 20   | 3000           | RoHS & Green | NIPDAU                        | Level-2-260C-1 YEAR | -40 to 85    | VA245                | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



# **PACKAGE OPTION ADDENDUM**

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(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

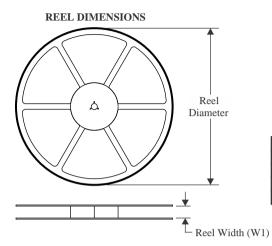
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**PACKAGE MATERIALS INFORMATION** 

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# TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device          | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-----------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74ALVC245DGVR | TVSOP           | DGV                | 20 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |
| SN74ALVC245DWR  | SOIC            | DW                 | 20 | 2000 | 330.0                    | 24.4                     | 10.8       | 13.3       | 2.7        | 12.0       | 24.0      | Q1               |
| SN74ALVC245NSR  | so              | NS                 | 20 | 2000 | 330.0                    | 24.4                     | 8.4        | 13.0       | 2.5        | 12.0       | 24.0      | Q1               |
| SN74ALVC245PWR  | TSSOP           | PW                 | 20 | 2000 | 330.0                    | 16.4                     | 6.95       | 7.1        | 1.6        | 8.0        | 16.0      | Q1               |
| SN74ALVC245RGYR | VQFN            | RGY                | 20 | 3000 | 330.0                    | 12.4                     | 3.8        | 4.8        | 1.6        | 8.0        | 12.0      | Q1               |



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### \*All dimensions are nominal

| 7 III GITTOTOTOTO GITO TIOTITICA |              |                 |      |      |             |            |             |
|----------------------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| Device                           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
| SN74ALVC245DGVR                  | TVSOP        | DGV             | 20   | 2000 | 356.0       | 356.0      | 35.0        |
| SN74ALVC245DWR                   | SOIC         | DW              | 20   | 2000 | 367.0       | 367.0      | 45.0        |
| SN74ALVC245NSR                   | so           | NS              | 20   | 2000 | 367.0       | 367.0      | 45.0        |
| SN74ALVC245PWR                   | TSSOP        | PW              | 20   | 2000 | 356.0       | 356.0      | 35.0        |
| SN74ALVC245RGYR                  | VQFN         | RGY             | 20   | 3000 | 356.0       | 356.0      | 35.0        |

# **PACKAGE MATERIALS INFORMATION**

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# **TUBE**

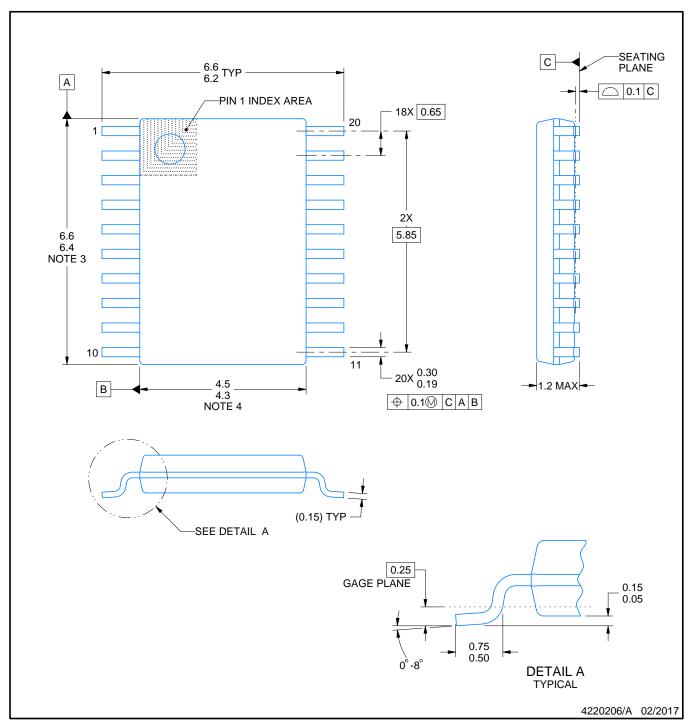


### \*All dimensions are nominal

| Device        | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| SN74ALVC245DW | DW           | SOIC         | 20   | 25  | 507    | 12.83  | 5080   | 6.6    |
| SN74ALVC245PW | PW           | TSSOP        | 20   | 70  | 530    | 10.2   | 3600   | 3.5    |



SMALL OUTLINE PACKAGE



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# DGV (R-PDSO-G\*\*)

### **24 PINS SHOWN**

### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.





SOIC



### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



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NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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